## EAST Search History

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|--------------|-----|------------------|---------|------------|
| L1 | 50 | (("5232569") or ("4916496") or ("5290323") or ("5433823") or ("5766446") or ("4385102") or ("4449285") or ("4478690") or ("4483694") or ("4555453") or ("4563806") or ("4576830") or ("4620772") or ("4761357") or ("4843451") or ("5017828") or ("5196725") or ("5196907") or ("5229313") or ("5230849") or ("5347766") or ("5493102") or ("5578503") or ("5625587") or ("5897790") or ("5925891") or ("6239005") or ("4258242") or ("4287383") or ("4305111") or ("4359488") or ("4365283") or ("4438188") or ("4447825") or ("4517227") or ("4538158") or ("4596722") or ("4596635") or ("4615908") or ("4756756") or ("4853346") or ("4910538") or ("4915978") or ("4962054") or ("4965090") or ("4968319") or ("4980306") or ("5007424") or ("5019469") or ("5019748")). PN. | US-PGPUB; USPAT; USOCR | OR | OFF | 2009/03/05 12:25 |
| L2 | 10067 | (438/149,151,157,161 or 257/40,57,384).ccls. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/03/05 12:27 |
| L3 | 4986 | L2 and @ad<"20030712" | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/03/05 12:27 |
| L4 | 2331 | L3 and (tft or (thin film transistor)) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/03/05 12:27 |
| L5 | 924 | L4 and ((dielectric or insulating) with layer with substrate with gate) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/03/05 12:27 |

| L6 | 48 | L5 and (coplanar with tft) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/03/05 12:28 |
|---|---|---|---|---|---|---|
| L7 | 61 | L5 and (coplanar with (tft or transistor)) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/03/05 12:28 |
| S1 | 40 | ((JOHN) near2 (RUDIN)).INV. | US-PGPUB; USPAT; USOCR | ADJ | ON | 2009/03/04 15:19 |
| S2 | 2 | (("5183780") or ("6326640")).PN. | US-PGPUB; USPAT; USOCR | OR | OFF | 2009/03/04 15:24 |
| S3 | 24 | ("4234356" \| "4400715" \| "4542580" \| "4651410").PN. OR ("5183780").URPN. | US-PGPUB; USPAT; USOCR | ADJ | ON | 2009/03/04 15:27 |
| S4 | 44 | ("4106951" \| "5468519" \| "5500537").PN. OR ("6326640").URPN. | US-PGPUB; USPAT; USOCR | ADJ | ON | 2009/03/04 15:31 |
| S5 | 19 | ("20010029098" \| "20020022299" \| "20020155729" \| "20020164835" \| "20030170937" \| "5567550" \| "5574291" \| "5677041" \| "5691089" \| "5705826" \| "5942374" \| "5946551" \| "6207472" \| "6300988" \| "6326640" \| "6429457" \| "6452207" \| "6528816").PN. OR ("7015502").URPN. | US-PGPUB; USPAT; USOCR | ADJ | ON | 2009/03/04 15:33 |
| S6 | 19 | ("5708130" \| "5962631" \| "6107452" \| "6169163" \| "6204515" \| "6372154").PN. OR ("6452207").URPN. | US-PGPUB; USPAT; USOCR | ADJ | ON | 2009/03/04 15:36 |
| S8 | 12 | ("20020045289" \| "20020086464" \| "20020093017" \| "20030059984" \| "20030092232" \| "20030108727" \| "20030211665" \| "3990926" \| "5388328" \| "6335539" \| "6344660" \| "6555411").PN. | US-PGPUB; USPAT; USOCR | ADJ | ON | 2009/03/04 15:40 |
| S9 | 48 | ("5693977" \| "6060338" \| "6107117").PN. OR ("6335539").URPN. | US-PGPUB; USPAT; USOCR | ADJ | ON | 2009/03/04 15:42 |
| S10 | 27 | S9 and @ad<"20030712" | US-PGPUB; USPAT; USOCR | ADJ | ON | 2009/03/04 15:43 |

| S13 | 10054 | (438/149,151,157,161 or 257/40,57,384).ccls. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/03/04 16:18 |
|-----|-------|---------------------------------------------|----------------------------------------------------------|-----|----|-------------------|
| S14 | 4986 | S13 and @ad< "20030712" | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/03/04 16:18 |
| S15 | 2331 | S14 and (tft or (thin film transistor)) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/03/04 16:18 |
| S16 | 232 | S15 and ((organic with (semiconductor or channel)) and ((resin or epoxy or flexible) with substrate)) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/03/04 16:19 |
| S17 | 10 | S15 and (electrolytic with deposit$3) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/03/04 16:20 |
| S18 | 266 | (tft or (thin film transistor)) and (source with drain with gate with layer with ("same" and common)) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/03/04 17:00 |
| S19 | 129 | S18 and @ad< "20030712" | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/03/04 17:00 |
| S20 | 555 | (tft or (thin film transistor)) and ((electrolytic with deposit $3) or (electro-deposit$3)) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/03/04 20:39 |
| S21 | 231 | S20 and @ad< "20030712" | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | ADJ | ON | 2009/03/04 20:40 |

**3/ 5/ 2009 12:28:56 PM**
**C:\ Documents and Settings\ rhuber\ My Documents\ EAST\ Workspaces\ Case 10564862 TFT w electrodes in layers\ EAST search TFT w electrodes in layers.wsp**